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Electronic Patent Application Submission  
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EFS ID: 20916  
Application ID: 10064232  
Title of Invention: Method For Producing Semi-  
Insulating Resistivity In High  
Purity Silicon Carbide Crystals  
First Named Inventor: Jason Jenny  
Domestic/Foreign Application: Domestic Application  
Filing Date: 2002-06-24  
Effective Receipt Date: 2002-12-17  
Submission Type: Information Disclosure Statement  
Filing Type: null  
Confirmation Number: 6381  
Attorney Docket Number: 5000.236  
Digital Certificate Holder: cn=Philip Summa, ou=Registered Attorneys, ou=Patent and  
Trademark Office, ou=Department of Commerce, o=U.S.  
Government, c=US  
Certificate Message Digest: y8Gz5LbbTGeukKaN61zNsw==

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Submission Type: Information  
Disclosure Statement

Application Number: 10/064,232  
Attorney Docket Number: 5000.236

## Method For Producing Semi-Insulating Resistivity In High Purity Silicon Carbide Crystals

First Named Inventor: Jason R. Jenny

### SUBMITTED BY

Name: Philip Summa  
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Date Signed: 20021217

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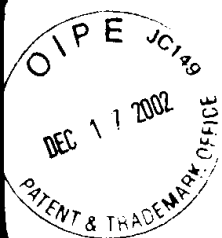
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### Attached Files:

us-information-disclosure-statement 5000236epaveids.xml

Comments:



# Electronic Information Disclosure Statement

## Method For Producing Semi-Insulating Resistivity In High Purity Silicon Carbide Crystals

Application:



10/064232

Confirmation:

6381

Applicant(s):

Jason Jenny

Docket Number:

5000.236

Group Art Unit:

1765

Examiner:

search string: (6218680 or 4866005 or 6403982 or 6396080 or 20010017374 or 20020167010 ).pn.

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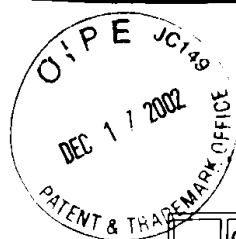
TC 1700

### US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Citation No.	Patent Number	Date	Bar Code	Patentee	Class	Subclass
	P01	6218680	2001-04-17		Carter	257	77
	P02	4866005	1989-09-12		Davis	437	100
	P03	6403982	2002-06-11		Carter	257	77
	P04	6396080	2002-05-28		Carter	257	77

### Published Applications



Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Citation No.	Patent Number	Date	Bar Code	Patentee	Class	Subclass
	U01	20010017374	2001-08-30		Carter	257	78
	U02	20020167010	2002-11-14		Mueller	257	77

## Signature

Examiner Name	Date

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